Diode Semiconductor Device - Page 1 of 1



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Inclosure Material: Glass and metal **Overall Length:** 6.000 inches **Overall Diameter:** 0.750 inches **Mounting Facility Quantity:** 2 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.138 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 25000.0 reverse voltage, peak **Current Rating Per Characteristic:** 8.00 amperes source cutoff current preset Maximum Operating Tempurature Per Measurement Point: 150.0 degrees celsius ambient air **Thread Series Designator:** Unc **Terminal Type And Quantity:** 2 turret Shelf Life: N/a Unit Of Measure: ---**Demilitarization:** No Fiig: A110a0